## 12mm × 12mm、5 轨应用处理器电源定序参考设计

# TEXAS INSTRUMENTS

#### 说明

该参考设计展现了一款经过验证的经济实惠型电源定序解决方案,适用于应用处理器或高性能控制平台。该解决方案可支持 5 个不同的电压轨,经过优化后,具备 12mm × 12mm 的布局空间。该设计还能调节延迟时间,为每个轨重新配置电压电平,从而适应不同的输入电容器和处理器要求。

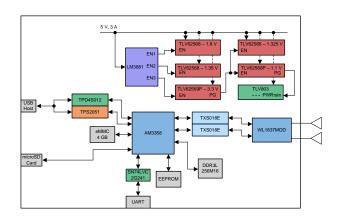
该参考设计基于 TI 的 AM335x 处理器和 WiLink8™模 块 WL1837MOD,可打造高性能的控制平台,有助于为 智能 设备或自动化应用带来更多的功能和更好的 性能。

#### 资源

| 设计文件夹 |
|-------|
| 产品文件夹 |
|       |



咨询我们的 E2E™ 专家



#### 特性

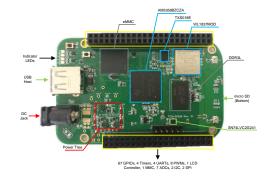
- 经过验证的电源定序解决方案
- 可配置的延迟时间选项
- 在各种负载情况下,即使对无法控制的断电,也能 提供正确的加电/断电序列
- 无论负载高低,均可保持电源树的高效率

 $(V_{IN}: 5V, I_{load}: 10mA)$ 

- 91%, 3.3V
- 84%, 1.8V
- 81%, 1.35V
- 81%, 1.325V
- 80%, 1.1V
- 电源布局空间小: 小于 12mm x 12mm
- 配备基于 ARM® Cortex®-A8 的内核,具有适用于增强型用户界面和灵活外设的 3D 图形 -
  - Sitara™AM335x
- 工业双频带 2 x 2 MIMO Wi-Fi®、低功耗 Bluetooth® 以及蓝牙智能模块 - WiLink WL183xMOD

#### 应用

- 冰箱
- 洗涤烘干机
- 壁挂式烤箱
- 扫地机器人
- 类人机器人
- 人机界面 (HMI)





System Description www.ti.com.cn



该 TI 参考设计末尾的重要声明表述了授权使用、知识产权问题和其他重要的免责声明和信息。

## 1 System Description

Smart appliances offer new features and high performance that have been integrated into appliances gradually, such as voice recognition, wireless connectivity, advanced Human Machine Interface (HMI), advanced interaction, and so forth. Processors with high performance and wireless connectivity devices are widely used in smart appliance control platforms. TI's Sitara<sup>™</sup> AM335x family and WiLink8<sup>™</sup> family are ideal choices for control systems in smart appliance.

The processors or digital devices usually require different power supply voltages, mixed together on the board with the correct power sequence. Power supply voltages turned on with an incorrect power sequence can cause reliability problems such as characteristics degradation, inrush currents, and latch-up conditions. The challenge is how to design the power tree with correct sequencing without trading off factors such as power tree architect, efficiency, cost, size, and more.

This reference design provides a 5-rail multi-channel power sequencing solution. The small form factor of 12 mm × 12 mm is achieved by using the TLV62568/9, offering 1.5-MHz switching frequency in a small package of SOT-563. The correct power sequence is achieved by using the LM3881, offering three opendrain output flags with individual time delays to avoid latch conditions or large inrush currents that can affect the reliability of the system. This power sequencing solution also supports the uncontrolled power off by using a supervisor of the TLV803 to monitor the input voltage rail, while also generating the power reset signal to manage the power up and power down sequence.

The test report evaluates this power sequencing platform, powering the AM335x and WL1837MOD with all necessary components as a system control platform such as: 4GB eMMC, 256M x 16-Bit DDR3L, microSD™ Card, EEPROM, and USB host. The test result provides the details of the power up and power down sequence, and the typical characters of DC-DCs.

#### 1.1 Key System Specifications

#### 表 1. Key System Specifications

| PARAMETER                              | SPECIFICATIONS  |
|--|---|
| Input voltage range                    | 3.3 V to 5.5 V  |
| Input power                            | 15 W  |
| Output voltage rails                   | 3.3 V / 2 A, 1.8 V / 1 A, 1.1 V / 1 A 1.35 V / 1 A, 1.325 V / 1 A                           |
| Voltage ripple                         | < 5% at 3.3 V, <5% at 1.8 V, <4% at 1.1 V, <5% at 1.35 V, <4% at 1.325 V                    |
| Power up/down Sequence                 | Meet requirements of the AM335x at "RTC Feature Disabled" mode and WL183xMOD's requirements |
| Efficiency at 5 V <sub>IN</sub>        | >95% at 3.3 V, >90% at 1.8 V, >87% at 1.1 V >89% at 1.35 V, >89% at 1.325 V                 |
| Efficiency at 10 mA, 5 V <sub>IN</sub> | >91% at 3.3 V, >84% at 1.8 V, >80% at 1.1 V >81% at 1.35 V, >81% at 1.325 V                 |
| Specification of board                 | 86 mm × 54 mm (12 mm × 12 mm for power part), 6 layer                                       |
| Operating ambient                      | -40°C to 85°C   |



## 2 System Overview

## 2.1 Block Diagram

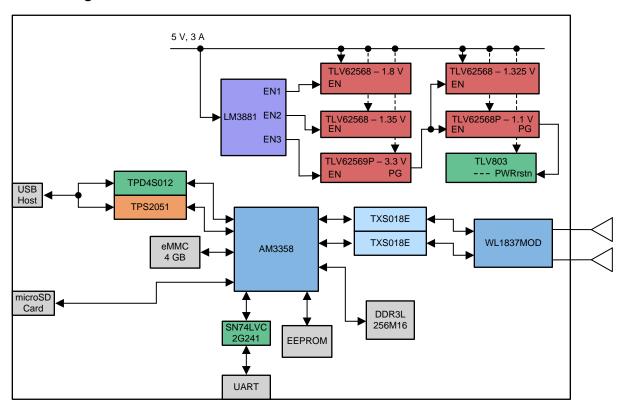


图 1. TIDA-01568 Block Diagram

## 2.2 Design Considerations

Before choosing or designing a power supply solution for application processors with a high level of complexity, the hardware engineer must understand the system power needs, then determine the architecture of the power tree to trade off efficiency, size, and cost.

## 2.2.1 Power Rails Requirements of the System

The considerations for power rails requirements consist of:

- Number of different power rails
- Load current of each rail
- Voltage rating
- Architecture of power tree



表 2 shows the basic power requirements of this system.

表 2. Basic Power Requirements

| Sequence     | Power Supply   | Device     | Nominal Rating | Max Current [mA] |
|--------------|--|------------|----------------|------------------|
| 4-up, 1-down | VDD_CORE   | AM335x     | 1.1 V ± 4%     | 400              |
| 4-up, 1-down | VDD_MPU  | AM335x     | 1.325 V ± 4%   | 1000             |
| 1-up, 4-down | VIO  | WL1837MOD  | 1.62 ~ 1.95    | < 400            |
| 1-up, 4-down | VDDS_SRAM_MPU_BB, VDDS_SRAM_CORE_BG, VDDA_ADC, VDDS_PLL_DDR, VDDS_PLL_MPU, VDDS_PLL_CORE_LCD, VDDS_OSC, VDDA1P8V_USB0, VDDA1P8V_USB1, VDDS | AM335x     | 1.8 V ± 5%     | 590              |
| 3-up, 2-down | VDDA_USB0, VDDA_USB1,<br>VDDSHVx   | AM335x     | 3.3 V ± 5%     | 370              |
| 3-up, 2-down | VBAT   | WL1837MOD  | 3.3 V          | 850              |
| 3-up, 2-down | V_NAND   | NAND Flash | 3.3 V          | 80               |
| 3-up, 2-down | Other Peripheral   | Board      | 3.3 V          | < 500            |
| 2-up, 3-down | VDDS_DDR, V_DDR3L  | DDR3L      | 1.35           | 250              |

In this system, the processor device on the board is the AM3358BZCZA. The operating performance points (OPPs) have been configured for "Nitro", which means the VDD\_MPU should be 1.325 V, enabling a 1-GHz speed grade. The recommended operating conditions are showed in Section 5.5 of the AM335x data sheet. The power consumption summary for each terminal is showed in Section 5.6 of the AM335x data sheet.

## 2.2.2 Power Sequencing Requirements of the System

Power sequencing requirements are another key consideration. The operation mode of this system has been set as RTC Feature Disable, the details of power sequencing requirements are shown in Figure 6-6 of AM335x data sheet. In this mode, consider the configuration for each pin related to RTC functionality when designing the schematic. The use case scenarios are provided in the AM335x\_Schematic\_Checklist.



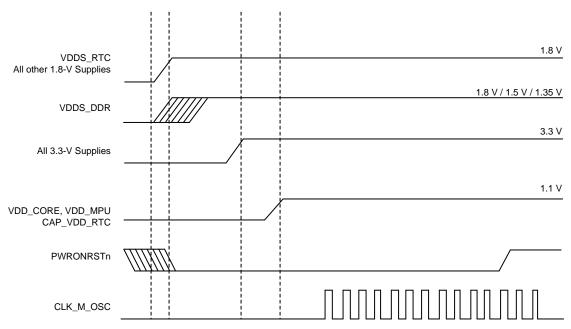


图 2. Power Supply Sequencing for AM335x with RTC Feature Disabled

The requirements for the power-up sequencing:

- 1. VDDS\_RTC and all other 1.8-V supplies ramp up.
- 2. VDD DDR, which has been set at 1.35 V, ramp up at second order.
- 3. All 3.3-V supplies ramp up at third order.
- 4. VDD\_CORE at 1.1 V and VDD\_MPU at 1.325 V ramp up after the 3.3-V rail goes high and at fourth order.
- 5. PWRONRSTn ramps up after all other rails go high.

The requirements for the power-down sequencing:

- 1. The PWRONRSTn input terminal should be taken low, which stops all internal clocks before the power supplies are turned off. All other external clocks to the device should be shut off.
- 2. The preferred method to sequence power down is to have all the power supplies ramped down sequentially in the exact reverse order of the power-up sequencing. In other words, the power supply that was ramped up first should be the last one to be ramped down. This ensures there are no spurious current paths during the power-down sequence. The VDDS power supply must ramp down after all 3.3-V VDDSHVx [1-6] power supplies.
- 3. If it is desired to ramp down VDDS and VDDSHVx[1-6] simultaneously, it should always be ensured that the difference between VDDS and VDDSHVx[1-6] during the entire power-down sequence is < 2 V. Any violation of this could cause reliability risks for the device. Further, TI recommends maintaining VDDS ≥ 1.5 V, as all the other supplies fully ramp down to minimize in-rush currents.
- 4. If none of the VDDSHVx [1-6] power supplies are configured as 3.3 V, the VDDS power supply may ramp down along with the VDDSHVx [1-6] supplies, or after all the VDDSHVx [1-6] supplies have ramped down. TI recommends maintaining VDDS ≥ 1.5 V, as all the other supplies fully ramp down to minimize in-rush currents.

The VBAT and VIO for the WL183xMOD do not have a strict requirement on which can come up first. However, there are strict requirements for the Enable and Clock power sequences, which are outlined on Section 5.22.2 of the WL18x7MOD data sheet.



#### 2.2.3 Uncontrolled Power Off

Uncontrolled power off is a situation when the power supply is removed unexpectedly, meaning the power supply rails' discharge time depends on the input capacitor and load current. The corresponding situation is controlled power off, which means the power off is controlled by software, achieved by connecting the processor's power management pin to the power sequencing controller's enable pin.

In an uncontrolled power-off situation, the discharging time is short and may cause the power-down sequence to be out of order. The most efficient method is to use a supervisor to monitor the input voltage, and generate the sudden flag indicating power off occurred.

In this design, the supervisor monitors the input voltage rail. When the input voltage rail ramps down, the output of supervisor -- POWERONRSTn goes low, which disables the main oscillator, reduces the load current, and increases the discharge time.



#### 2.2.4 12-V Input Voltage Rail

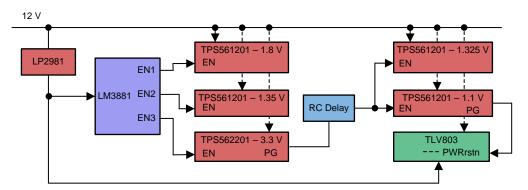


图 3. Power Sequencing Platform Diagram at 12-V Input Voltage Rail

An extra LDO and RC delay circuit should be added in the new architecture of the power tree with the 12-V input voltage rail. The LDO provides power for the sequencer, and the supervisor monitors the LDO's output voltage, which represents the input voltage rail's change.

## 2.3 Highlighted Products

For more information on each of the devices listed below, see their respective product folders at www.ti.com.

#### 2.3.1 TLV62568/9

This reference design selected the TLV62568 with a 1-A output current and the TLV62569P with a 2-A output current.

The TLV62568/9 is a high-efficiency synchronous step-down converter. The device operates with an adaptive off time with a peak current control scheme. The device typically operates at a 1.5-MHz frequency pulse width modulation (PWM), at moderate to heavy load currents. Based on the VIN/VOUT ratio, a simple circuit sets the required off time for the low-side MOSFET, making the switching frequency relatively constant regardless of the variation of input voltage, output voltage, and load current.



🛚 4 shows the functional block diagram of the TLV62568, and as a reference diagram for the TLV62569.

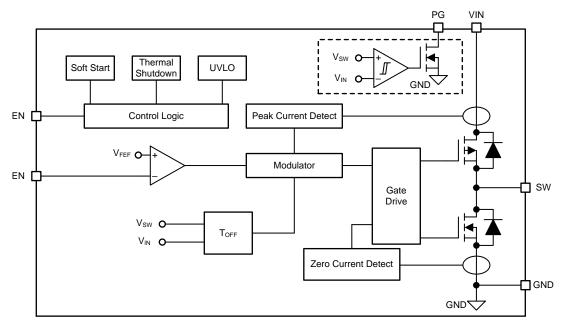


图 4. TLV62568 Functional Block Diagram

#### Features:

- Up to 95% Efficiency
- Low R DS(ON) Switches 150 mΩ / 100 mΩ
- 2.5-V to 5.5-V Input Voltage Range
- Adjustable Output Voltage from 0.6 V to VIN
- Power Save Mode for Light Load Efficiency
- 100% Duty Cycle for Lowest Dropout
- 35-µA Operating Quiescent Current
- 1.5-MHz Switching Frequency
- Power Good Output
- Over Current Protection
- Internal Soft Startup
- Thermal Shutdown Protection
- Available in SOT Package
- Pin-to-Pin Compatible with TLV62569



#### 2.3.2 LM3881

The LM3881 Simple Power Sequencer provides a simple solution for sequencing multiple rails in a controlled manner. An established clock signal facilitates control of the power up and power down of three open-drain FET output flags. These flags permit a connection to the shutdown or enable pins of the linear regulators or switching regulators to control the operation of the power supplies. This allows the design of a complete power system without the concern of large inrush currents or latch-up conditions that can occur during an uncontrolled startup. An invert (INV) pin reverses the logic of the output flags. This pin should be tied to a logic output high or low, and not be allowed to remain an open circuit. The following sections assume that the INV pin is held low such that the flag output is active high.

§ 5 shows the functional block diagram of the LM3881.

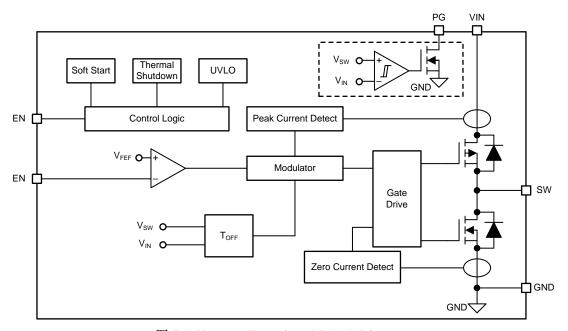


图 5. LM38881 Functional Block Diagram

#### Features:

- Easy Method to Sequence Rails
- Power-Up and Power-Down Control
- Tiny Footprint
- Low Quiescent Current of 80 μA
- Input Voltage Range of 2.7 V to 5.5 V
- Output Invert Feature
- Timing Controlled by Small Value External Capacitor



#### 2.3.3 TLV803

The TLV803 family of supervisory circuits provides circuit initialization and timing supervision. The TLV853 and TLV863 are both functionally equivalent to the TLV803. These devices output a logic low when VDD drops below the negative-going threshold voltage (VIT–). The output, RESET, remains low for approximately 200 ms after the VDD voltage exceeds the positive-going threshold voltage (VIT– + Vhys). These devices are designed to ignore fast transients on the VDD pin.

图 6 shows the functional block diagram of the TLV803.

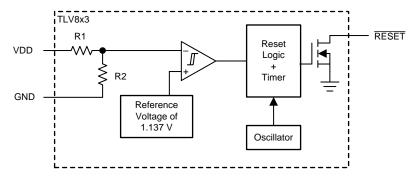


图 6. TLV803 Functional Block Diagram

#### Features:

- 3-Pin SOT23 Package
- Supply Current: 9 μA (Typical)
- Precision Supply Voltage Monitor: 2.5 V, 3 V, 3.3 V, 5 V
- Power-On Reset Generator with Fixed Delay Time of 200 ms
- Temperature Range: –40°C to +125°C
- Open-Drain, RESET Output

#### 2.3.4 AM335x

The AM335x microprocessors, based on the ARM Cortex-A8 processor, are enhanced with image, graphics processing, peripherals, and industrial interface options such as EtherCAT and PROFIBUS. The devices support high-level operating systems (HLOS). Linux® and Android™ are available free of charge from TI.

The microprocessor unit (MPU) subsystem is based on the ARM Cortex-A8 processor and the PowerVR SGX<sup>™</sup> Graphics Accelerator subsystem provides 3D graphics acceleration to support display and gaming effects.

The PRU-ICSS is separate from the ARM core, allowing independent operation and clocking for greater efficiency and flexibility. The PRU-ICSS enables additional peripheral interfaces and real-time protocols such as EtherCAT, PROFINET, EtherNet/IP, PROFIBUS, Ethernet Powerlink, Sercos, and others. Additionally, the programmable nature of the PRU-ICSS, along with its access to pins, events, and all system-on-chip (SoC) resources, provides flexibility in implementing fast, real-time responses, specialized data handling operations, custom peripheral interfaces, and in offloading tasks from the other processor cores of SoC.



图 7 shows the functional block diagram of the AM335x.

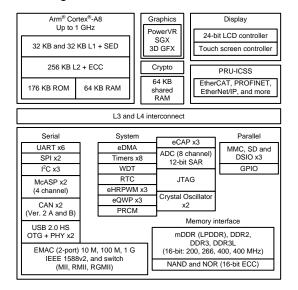


图 7. AM335x Functional Block Diagram

#### 2.3.5 WL1837MOD

The certified WiLink 8 module from TI offers high throughput and extended range, along with Wi-Fi and Bluetooth coexistence (WL1837MOD only) in a power-optimized design. The WL18x7MOD is a Wi-Fi, dual-band, 2.4- and 5-GHz module solution with two antennas supporting Industrial temperature grade. The device is FCC, IC, ETSI/CE, and TELEC certified for AP (with DFS support) and client. TI offers drivers for high-level operating systems, such as Linux and Android. Additional drivers, such as WinCE and RTOS, which includes QNX, Nucleus, ThreadX, and FreeRTOS, are supported through third parties.

8 shows the functional block diagram of the WL1837MOD.



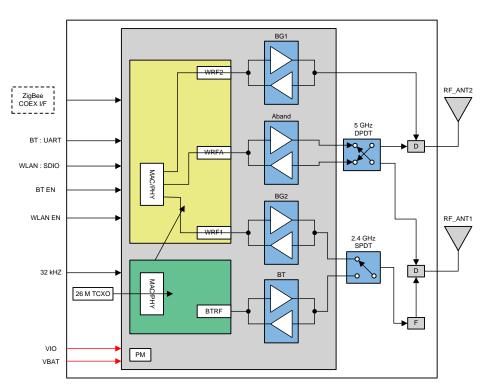


图 8. WL1837MOD Functional Block Diagram



## 2.4 System Design Theory

#### 2.4.1 Power Tree Architecture

This design provides an efficient power tree architecture, as shown in № 9. The input voltage rail of 5 V is configured as the power supply for each part; power-up sequence and power-down sequence are divided into 5 orders, as shown in † 2.2.2. The power sequence controller is achieved by a sequencer and a supervisor. The sequence order of VDD\_MPU and VDD\_CORE is achieved by leveraging the 3.3-V converter's power good signal.

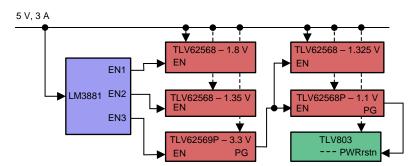


图 9. Power Sequencing Platform Diagram

## 2.4.2 Power Sequencing Solution



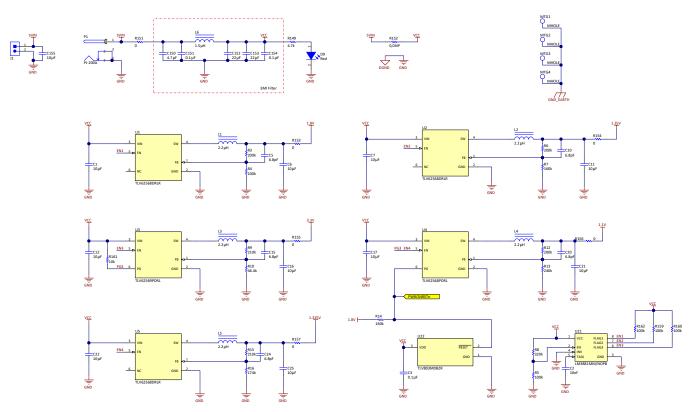


图 10. Power Sequencing Circuit

#### 2.4.2.1 Design Steps for DC-DCs

Select the circuit topology. The cost, space, and efficiency are key concerns in home appliance design, so select a Buck topology. Use a synchronous converter with integrated FET and high switching frequency to reduce the bill of material cost and size.

Then, select the TLV62568/9. The TLV62568/9 is a high efficiency synchronous converter in a SOT563 package, and typically operates at a 1.5-MHz frequency pulse width modulation (PWM) at moderate to heavy load currents. At light load, the device automatically enters Power Save Mode (PSM) to maintain high efficiency.

Next, set the output voltage, which is adjusted by the resistor divider, as shown in  $\triangle \mathbb{R}$  1. A reference design example is for a 1.8-V power supply, when sizing R4, to achieve low current consumption and acceptable noise sensitivity, to use a maximum of 200 k $\Omega$  for R4. Larger currents through R4 improve noise sensitivity and output voltage accuracy, but increase current consumption. In this design, 100 k $\Omega$  is selected for R4.

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R_2}{R_4}\right) = 0.6 \text{ V} \times \left(1 + \frac{R_2}{R_4}\right)$$
 (1)

A feed forward capacitor, C5 of 6.8 pF, is recommended for improving the loop bandwidth to make a fast transient response.

The inductor and output capacitor together provide a low-pass filter. The inductor peak-to-peak ripple current, peak current, and the RMS current are calculated using 公式 2, 公式 3, and 公式 4.



$$II_{p-p} = \frac{V_{OUT}}{V_{IN(max)}} \times \frac{V_{IN(max)} - V_{OUT}}{L_O \times F_{SW}}$$
(2)

$$II_{peak} = I_O + \frac{II_{p-p}}{2} \tag{3}$$

$$I_{LO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}}$$
(4)

The inductor saturation current rating must be greater than the calculated peak current, and the RMS or heating current rating must be greater than the calculated RMS current. Use 1.5 MHz for  $f_{SW}$ . Ensure the chosen inductor is rated for the peak current of  $\triangle \vec{\pi}$  3 and the RMS current of  $\triangle \vec{\pi}$  4.

For this design, the inductor used is the DFE252010F-2R2M=P2 (2.2  $\mu$ H), with a peak current rating of 3.3 A and RMS current rating of 2.3 A.

The capacitor value and ESR determines the amount of output voltage ripple. The TLV62568 is intended for use with ceramic or other low-ESR capacitors. Use  $\triangle \exists 5$  to determine the required RMS current rating for the output capacitor.

$$I_{LO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}}$$
(5)

For this design, a Murata 10-µF output capacitor is used.



## 2.4.2.2 Design Steps for the Sequencer

Select the suitable sequencer offering 3 power up and power down sequencing orders in regard to the power tree architecture. Cost, space, and ease-of-use are the key concerns for the sequencer.

In this design, the LM3881 provides a simple solution for sequencing multiple rails in a controlled manner. A small external timing capacitor (C2) establishes the clock waveform; the relationship between the capacitor and the clock period is typically 120  $\mu$ s/nF. In this design, a 10-nF capacitor is used, which means the clock period is 1.2 ms. The delay time between the 3 flags is 8 clock cycles, which means the interval time between power rails is 9.6 ms.

A resistor divider can also be used to enable the LM3881, based on exceeding a certain VCC supply voltage threshold. The supply voltage for which EN is asserted is given in 公式 6.

$$VCC_{ENABLE} = 1.22 \text{ V} \times \left(1 + \frac{R_{EN1}}{R_{EN2}}\right) - 7 \text{ } \mu\text{A} \times \left(R_{EN1} \|R_{EN2}\right) \tag{6}$$

By tuning the capacitor, the delay time can be adjusted for a different discharge time. By tuning the VCC supply voltage threshold, the moment when the sequencer works also can be adjusted for a different discharge time.

#### 2.4.2.3 Design Steps for the Supervisor

The TLV803 is chosen as the supervisor in this design. The LM803M's reset pin is connected to a 1.1-V converter's power good pin, which ensures the reset signal ramps up after all the power rails go high.



## 3 Hardware, Software, Testing Requirements, and Test Results

#### 3.1 Required Hardware and Software

#### 3.1.1 Hardware

#### 3.1.1.1 Connector Configuration of TIDA-01568

shows the top view of the PCB and connector configuration for this reference design, which features:

- A two-terminal input for power supply (J1): This pin is used to connect the input DC supply. The positive and negative terminals are also shown in .
- A six-pin connector for UART (J2): Three of the pins are used for external UART communication with a
  host machine. This interface is usually used for monitoring booting information during Linux software
  development.
- System Reset (S1): This switch is used to reset the processors.
- Boot Mode Configuration (S2): This switch is used to change boot mode between two modes. The usual operation is to change boot from the on-board flash to an external microSD card.
- Expansion headers (P8,P9): These two headers lead out the processors' available GPIOs and on-chip resources, which can be used for expand functions, including 67 GPIOs, 4 timers, 4 UARTs, 8 PWMs, 1 24-bit LCD controller, 1 MMC, 7 ADCs, 2 I2Cs, and 2 SPIs.
- PFC Antenna: These two terminals are used for installing 2.4G / 5G PFC antennas in UFL/IPEX-1 type.

| 表 3. Expansion Hea | aders – P8 |
|--------------------|------------|
|--------------------|------------|

| DGND                               | 1  | 2  | DGND                                    |
|------------------------------------|----|----|---|
| GPIO1_6                            | 3  | 4  | GPIO1_7                                 |
| GPIO1_2                            | 5  | 6  | GPIO1_3                                 |
| GPIO2_2 TIMER4                     | 7  | 8  | GPIO2_3 TIMER7                          |
| GPIO2_5 TIMER5                     | 9  | 10 | GPIO2_4 TIMER6                          |
| GPIO1_13 LCD_DATA18                | 11 | 12 | GPIO1_12 LCD_DATA19                     |
| GPIO0_23 EHRPWM2B LCD_DATA22       | 13 | 14 | GPIO0_26 LCD_DATA21                     |
| GPIO1_15 LCD_DATA16                | 15 | 16 | GPIO1_14 LCD_DATA17                     |
| GPIO0_27 LCD_DATA20                | 17 | 18 | GPIO2_1                                 |
| GPIO0_22 EHRPWM2A LCD_DATA23       | 19 | 20 | GPIO1_31 MMC1_CMD                       |
| GPIO1_30 MMC1_CLK                  | 21 | 22 | GPIO1_5 MMC1_DAT5                       |
| GPIO1_4 MMC1_DAT4                  | 23 | 24 | GPIO1_1 MMC1_DAT1                       |
| GPIO1_0 MMC1_DAT0                  | 25 | 26 | GPIO1_29                                |
| GPIO2_22 LCD_VSYNC                 | 27 | 28 | GPIO2_24 LCD_PCLK                       |
| GPIO2_23 LCD_HSYNC                 | 29 | 30 | GPIO2_25 LCD_DE                         |
| GPIO0_10 LCD_DATA14<br>UART5_CTSN+ | 31 | 32 | GPIO0_11 LCD_DATA15 UART5_RTSN          |
| GPIO0_9 LCD_DATA13 UART4_RTSN      | 33 | 34 | GPIO2_17 LCD_DATA11 EHRPWM1B UART3_RTSN |
| GPIO0_8 LCD_DATA12 UART4_CTSN      | 35 | 36 | GPIO2_16 LCD_DATA10 EHRPWM1A UART3_CTSN |
| GPIO2_14 LCD_DATA8 UART5_TXD+      | 37 | 38 | GPIO2_13 LCD_DATA9 UART5_RXD+           |
| GPIO2_12 LCD_DATA6                 | 39 | 40 | GPIO2_11 LCD_DATA7                      |
| GPIO2_10 LCD_DATA4                 | 41 | 42 | GPIO2_9 LCD_DATA5                       |
| GPIO2_8 LCD_DATA2                  | 43 | 44 | GPIO2_7 LCD_DATA3                       |
| GPIO2_6 LCD_DATA0 EHRPWM2A         | 45 | 46 | GPIO2_5 LCD_DATA1 EHRPWM2B              |



#### 表 4. Expansion Headers - P9

| DGND   | 1  | 2  | DGND   |
|--|----|----|--|
| 3.3V   | 3  | 4  | 3.3V   |
| 5.0V   | 5  | 6  | 5.0V   |
| 5.0V   | 7  | 8  | 5.0V   |
| EXTINTn  | 9  | 10 | SYS_RESETn                                       |
| GPIO0_30 UART4_RXD                             | 11 | 12 | GPIO1_28   |
| GPIO0_31 UART4_TXD                             | 13 | 14 | GPIO1_18 EHRPWM1A                                |
| GPIO1_16                                       | 15 | 16 | GPIO1_19 EHRPWM1B                                |
| GPIO0_5 I2C1_SCL SPI1_CS0                      | 17 | 18 | GPIO0_4 I2C1_SDA SPI1_D1                         |
| GPIO0_13 I2C2_SCL UART1_RTSn<br>SPI1_CS1       | 19 | 20 | GPIO0_12 I2C2_SDA UART1_CTSn SPI1_CS0            |
| I2C2_SCL SPI0_D0 GPIO0_3<br>UART2_TXD EHRPWM0B | 21 | 22 | SPI0_SCLK GPIO0_2 UART2_RXD EHRPWM0A<br>I2C2_SDA |
| GPIO1_17                                       | 23 | 24 | GPIO0_15 UART1_TXD I2C1_SCL                      |
| GPIO3_21                                       | 25 | 26 | GPIO0_14 UART1_RXD I2C2_SDA                      |
| GPIO3_19                                       | 27 | 28 | GPIO3_17 SPI1_CS0 ECAPPWM2                       |
| GPIO3_15 SPI1_D0 EHRPWM0B                      | 29 | 30 | GPIO3_16 SPI1_D1                                 |
| GPIO3_14 SPI1_SCLK EHRPWM0A                    | 31 | 32 | VDD_ADC  |
| AIN6   | 33 | 34 | GNDA_ADC   |
| AIN4   | 35 | 36 | AIN5   |
| AIN2   | 37 | 38 | AIN3   |
| AIN0   | 39 | 40 | AIN1   |
| GPIO0_20                                       | 41 | 42 | GPIO0_7 ECAPPWM0 SPI1_CS1                        |
| DGND   | 43 | 44 | DGND   |
| DGND   | 45 | 46 | DGND   |

## 3.1.1.2 Procedure for Board Bring-up and Testing

Follow this procedure for board bring-up and testing:

- 1. Configure the developing environment; for details, refer to the Processor SDK Getting Started Guide.
- 2. After setting the correct configuration, modify the processor SDK by installing patch files for this reference design.
- 3. Connect the board to the host machine through a UART to USB cable; configure the UART debug tools (super terminal, tera term, and so forth) with the correct serial port. Insert a microSD card containing an image of the modified Linux operating system.
- 4. Power on the board on the voltage supply input with a 5-V DC.



#### 3.1.2 Software

## 3.1.2.1 Description of Environment Implementation

This section describes the details of developing an environment implemented during the Linux operation system bringing up, listed in  $\frac{1}{8}$  5.

| Environment Components                 | Description  |
|--|--|
| Ubuntu 16.04.3                         | Linux host's version (the LTS version is preferred)  |
| Processor-SDK-Linux-AM335x 04_02_00_09 | The version of published SDK used in this design, patch files are compatible with this version |
| Code Composer Studio 7.2.0             | Using as the add-on debug tool for AM335x  |
| u-boot_tida_01568.patch                | A patch file for boot loader to support this design  |
| linux_tida_01568_without_wifi.patch    | A patch file for Linux kernel to support this design, no WIFI driver support                   |
| linux tida 01568 with wifi.patch       | A patch file for Linux kernel to support this design, WIFI driver support                      |

表 5. Development Environment Description

#### 3.1.2.2 How to Customize the Processor SDK for This Reference Design

An operating system is necessary in most applications to manage hardware and software resources, while the released kernel carries rich features or low-level drivers that may not fit the user's hardware. For this reference design, run the fit kernel on board by applying a patch to processor SDK. 图 11 shows the instructions used for this process.

```
bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/u-boot-2017.01+gitAUTOINC+340fb36f04-g340fb36f045 patch -p2 < u-boot_tida_0
patching file arch/arn/mach-omap2/am33xx/board.c
patching file board/ti/am335x/board.c
patching file board/ti/am335x/board.c
patching file board/ti/am335x/board.h
patching file board/ti/am335x/board.c
patching file board/ti/am335x/board.b
patching file include/configs/am335x_evm.h
bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe93055

port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe93055

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe93055

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305-ga75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+gitAUTOINC+a75dBe9305$

bryan@bryan-VirtualBox:-/ti-processor-sdk-linux-am335x-evm-04.02.00.09/board-sup
port/linux-4.9.59+
```

图 11. How to Apply a Patch to the Processor SDK

Comparing to the AM335x EVM or Beagle Bone family, the differences in hardware are:

- The EEPROM on this board does not contain the information of board ID.
- This board does not support the internal RTC.
- This board does not support the PMIC IC for power management.

The brief principle of modified codes behind the patch files:

- 1. U-Boot: Disable the board detect function and enforce the return value for "am335x-boneblack".
- 2. U-Boot: Disable the I2C communication with PMIC.
- 3. U-Boot: Disable the RTC related function.
- 4. U-Boot: Disable the "BOOTCOUNT LIMIT" configuration during auto booting.



- 5. Kernel: Remove the RTC node, PMIC node and related codes in device tree (DTS file).
- 6. Kernel: Disable the "RTC Real Time Clocking" configuration.
- 7. Kernel: Add WL1837MOD driver configuration.

#### 3.1.3 Software Bring-up Tips

- 1. Before developing the software, ensure the hardware is working correctly: consequent CCCC's should print on the screen when the SD card is not inserted.
- 2. Code Composer Studio is a tool used for tracking the instructions executed during bringing up the software. The terminal of P2 on the bottom of the board is a JTAG header to connect the emulator. The System.map file is a symbol table, which is a look-up between symbol names and their addresses in memory. Combining the symbol table and memory data lets the user track the process of how the software is running.

## 3.2 Testing and Results

#### 3.2.1 Test Setup

The test performs the power-up and power-down sequencing, with a DC source and a switch that simulate the situation when removing the DC power. 

12 shows the test setup.

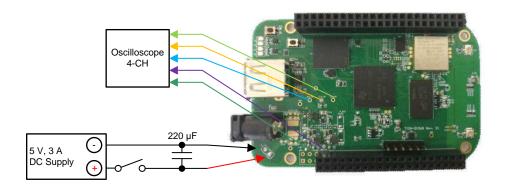


图 12. Power Sequencing Test Setup

#### 3.2.2 Test Results

## 3.2.2.1 Power-Up and Power-Down Sequence Test

The following waveforms show the power-up and power-down sequence provided by this power solution that meet the requirements of the AM335x. The test environment is as below:

- 1. The input capacitor is 220 μF.
- 2. The status of the board is: Linux running with Wi-Fi enabled.
- 3. The style of the power down directly removes the DC power through the switch.



图 13 shows the power sequences of the input voltage rail and 1.8-V, 3.3-V, and 1.35-V rails.

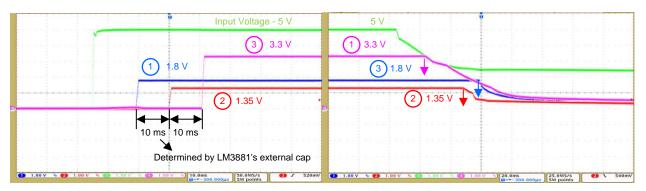


图 13. Power Sequence for 5-Vin,1.8-V, 3.3-V, and 1.35-V Rails

For the power-up sequencing, the 1.8-V, 1.35-V, and 3.3-V rails power turn on sequentially after the input voltage rail turns on. For the power-down sequencing, the 3.3-V, 1.35-V, and 1.8-V rails turn off sequentially in the precise reverse order after the input voltage rail turns off. The delay time between the different power rails is approximately 10 ms, which can be adjusted by changing the external capacitor of the LM3881MM.

14 shows the power sequences of the 3.3-V, 1.8-V, 1.35-V, and 1.1-V rails.

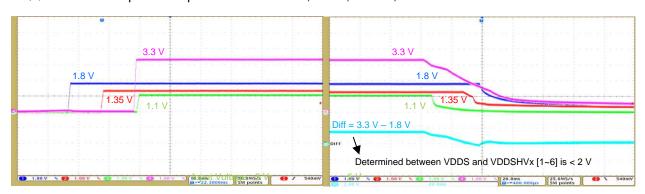


图 14. Power Sequence for 3.3-V, 1.8-V, 1.35-V, and 1.1-V Rails

For the power-up sequencing, the 1.8-V, 1.35-V, and 3.3-V rails power turn on sequentially after the input voltage rail turns on. For the power-down sequencing, the 3.3-V, 1.35-V, and 1.8-V rails turn off sequentially in the precise reverse order after the input voltage rail turns off. The difference between VDDS and VDDSHVx[1-6] during the entire power down sequence is < 2 V.

图 15 shows the power sequences of the 5-Vin, 1.8-V, 3.3-V, and PWRONRSTn rails.



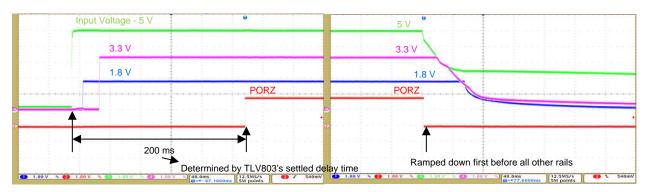


图 15. Power Sequence for 5-Vin, 1.8-V, 3.3-V, and PWRONRSTn Rails

For the power-up sequencing, the 1.8-V, 3.3-V, and PWRONRSTn rails turn on sequentially after the input voltage rail turns on, and the PWRONRSTn rail turns on after all the other rails are ON. For the power-down sequencing, the PWRONRSTn rail ramps down first before all other rails turn off, and the other rails ramp down sequentially. The delay time between PWRONRSTn and input voltage rail is 200 ms, which depends on the fixed delay time of the supervisor for the TLV803.

图 16 shows the power sequences of the 1.8-V, 3.3-V, 1.1-V, and 1.325-V rails.

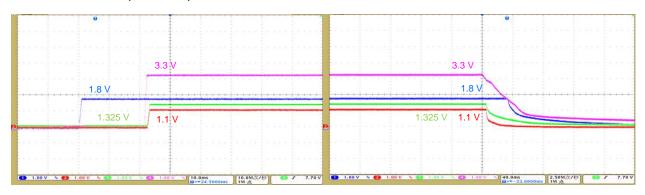


图 16. Power Sequence for 1.8-V, 3.3-V, 1.1-V, and 1.325-V Rails

For the power-up sequencing, the 1.8-V, 3.3-V, 1.1-V, and 1.325-V rails turn on sequentially, and the 1.325-V and 1.1-V rails ramp up at the same time. For the power-down sequencing, the 1.8-V, 3.3-V, 1.1-V, and 1.325-V rails ramp down sequentially, and the 1.325-V and 1.1-V rails ramp down at the same time.

#### 3.2.2.2 Typical Characteristics of DC-DCs

17 shows the efficiency of the 5 voltage rails with 5-V DC supply.



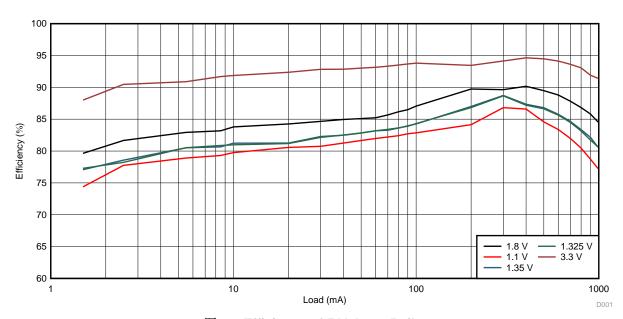


图 17. Efficiency of 5 Voltage Rails

To test the efficiency, four multimeters are used: two are set up as voltmeters to measure the input and output voltages, and two are set up as ammeters to measure the input and output currents. In addition, an electronic load is used to achieve different currents.



表 6. Efficiency of 1.8-V Rail

| V <sub>IN</sub> (V) | I <sub>IN</sub> (mA) | V <sub>OUT</sub> (V) | I <sub>OUT</sub> (V) | η(%)  |
|---------------------|----------------------|----------------------|----------------------|-------|
| 4.972               | 4.55                 | 1.807                | 10.49                | 83.79 |
| 4.949               | 8.52                 | 1.806                | 19.67                | 84.25 |
| 4.924               | 12.97                | 1.804                | 29.97                | 84.66 |
| 4.899               | 17.28                | 1.802                | 39.91                | 84.95 |
| 4.876               | 21.38                | 1.802                | 49.23                | 85.10 |
| 4.85                | 25.95                | 1.802                | 59.52                | 85.22 |
| 4.823               | 30.66                | 1.802                | 70.3                 | 85.67 |
| 4.798               | 34.91                | 1.801                | 80.13                | 86.16 |
| 4.773               | 39.31                | 1.796                | 90.36                | 86.49 |
| 4.749               | 43.53                | 1.796                | 100.2                | 87.05 |
| 4.491               | 88.58                | 1.789                | 199.55               | 89.74 |
| 4.911               | 121.1                | 1.785                | 298.65               | 89.64 |
| 4.883               | 160.1                | 1.78                 | 396                  | 90.16 |
| 4.85                | 206.68               | 1.775                | 505.3                | 89.48 |
| 4.822               | 245.64               | 1.77                 | 594.23               | 88.80 |
| 4.786               | 295.55               | 1.765                | 703.75               | 87.81 |
| 4.754               | 339.95               | 1.76                 | 797.25               | 86.82 |
| 4.718               | 388.68               | 1.756                | 896.17               | 85.82 |
| 4.718               | 440.6                | 1.75                 | 1003                 | 84.44 |

## 表 7. Efficiency of 1.1-V Rail

| V <sub>IN</sub> (V) | I <sub>IN</sub> (mA) | V <sub>out</sub> (V) | I <sub>OUT</sub> (V) | η(%)  |
|---------------------|----------------------|----------------------|----------------------|-------|
| 5.02                | 2.74                 | 1.0883               | 10.08                | 79.75 |
| 5                   | 5.52                 | 1.09                 | 20.4                 | 80.57 |
| 4.988               | 8.22                 | 1.09                 | 30.37                | 80.74 |
| 4.974               | 10.73                | 1.089                | 39.82                | 81.25 |
| 4.958               | 13.53                | 1.087                | 50.39                | 81.65 |
| 4.942               | 16.23                | 1.086                | 60.54                | 81.97 |
| 4.927               | 18.95                | 1.085                | 70.74                | 82.21 |
| 4.913               | 21.36                | 1.084                | 79.78                | 82.41 |
| 4.896               | 24.24                | 1.083                | 90.64                | 82.71 |
| 4.881               | 26.99                | 1.082                | 100.88               | 82.86 |
| 4.715               | 55.97                | 1.073                | 206.93               | 84.14 |
| 4.574               | 80.63                | 1.0688               | 299.54               | 86.81 |
| 4.395               | 111.8                | 1.064                | 399.9                | 86.59 |
| 4.944               | 126.74               | 1.0595               | 500.17               | 84.57 |
| 4.924               | 154.4                | 1.055                | 600.9                | 83.39 |
| 4.904               | 182.63               | 1.05                 | 699.15               | 81.97 |
| 4.881               | 213.6                | 1.046                | 802                  | 80.46 |
| 4.858               | 245.66               | 1.04                 | 903.47               | 78.73 |
| 4.834               | 278.5                | 1.036                | 1002                 | 77.11 |



## 表 8. Efficiency of 3.3-V Rail

| V <sub>IN</sub> (V) | I <sub>IN</sub> (mA) | V <sub>OUT</sub> (V) | I <sub>OUT</sub> (V) | η(%)  |
|---------------------|----------------------|----------------------|----------------------|-------|
| 4.968               | 7.6                  | 3.319                | 10.45                | 91.86 |
| 4.93                | 14.18                | 3.318                | 19.46                | 92.36 |
| 4.885               | 21.9                 | 3.317                | 29.94                | 92.83 |
| 4.846               | 28.69                | 3.314                | 38.95                | 92.84 |
| 4.8                 | 36.67                | 3.313                | 49.42                | 93.02 |
| 4.753               | 44.79                | 3.31                 | 59.91                | 93.15 |
| 4.712               | 51.88                | 3.31                 | 68.92                | 93.32 |
| 4.663               | 60.28                | 3.31                 | 79.4                 | 93.50 |
| 4.613               | 68.85                | 3.31                 | 89.88                | 93.67 |
| 4.57                | 76.37                | 3.31                 | 98.9                 | 93.80 |
| 4.898               | 143.46               | 3.296                | 199.21               | 93.44 |
| 4.84                | 216.12               | 3.2866               | 299.6                | 94.13 |
| 4.78                | 289.16               | 3.2823               | 398.51               | 94.63 |
| 4.715               | 367.1                | 3.2778               | 498.89               | 94.48 |
| 4.643               | 448.84               | 3.2736               | 599.17               | 94.12 |
| 4.565               | 534.06               | 3.2695               | 698.05               | 93.61 |
| 4.472               | 626.51               | 3.2655               | 798.38               | 93.05 |
| 4.276               | 746                  | 3.262                | 898.72               | 91.90 |
| 4.18                | 853.2                | 3.2585               | 1000                 | 91.37 |

## 表 9. Efficiency of 1.35-V Rail

| V <sub>IN</sub> (V) | I <sub>IN</sub> (mA) | V <sub>OUT</sub> (V) | I <sub>OUT</sub> (V) | η(%)  |
|---------------------|----------------------|----------------------|----------------------|-------|
| 4.992               | 3.57                 | 1.353                | 10.7                 | 81.23 |
| 4.974               | 6.66                 | 1.356                | 19.85                | 81.25 |
| 4.955               | 10                   | 1.3545               | 30.1                 | 82.28 |
| 4.935               | 13.51                | 1.3531               | 40.64                | 82.48 |
| 4.917               | 16.59                | 1.352                | 49.97                | 82.82 |
| 4.898               | 20                   | 1.3512               | 60.3                 | 83.17 |
| 4.879               | 23.21                | 1.351                | 69.8                 | 83.27 |
| 4.859               | 26.7                 | 1.35                 | 80.34                | 83.60 |
| 4.839               | 30.31                | 1.348                | 91.36                | 83.97 |
| 4.823               | 32.97                | 1.347                | 99.46                | 84.25 |
| 4.63                | 66.54                | 1.34                 | 200                  | 86.99 |
| 4.432               | 101.27               | 1.3344               | 298.44               | 88.73 |
| 4.923               | 122.96               | 1.3296               | 397.66               | 87.35 |
| 4.9                 | 155.16               | 1.325                | 498.08               | 86.80 |
| 4.873               | 191.27               | 1.3196               | 605.8                | 85.77 |
| 4.848               | 225.04               | 1.315                | 702.2                | 84.64 |
| 4.823               | 260.34               | 1.31                 | 798.94               | 83.35 |
| 4.793               | 300                  | 1.305                | 905.32               | 82.16 |
| 4.764               | 340.2                | 1.3                  | 1003                 | 80.45 |



## 表 10. Efficiency of 1.325-V Rail

| V <sub>IN</sub> (V) | I <sub>IN</sub> (mA) | V <sub>out</sub> (V) | I <sub>OUT</sub> (V) | η(%)  |
|---------------------|----------------------|----------------------|----------------------|-------|
| 4.993               | 3.42                 | 1.322                | 10.46                | 80.98 |
| 4.976               | 6.38                 | 1.325                | 19.45                | 81.18 |
| 4.956               | 9.73                 | 1.323                | 29.94                | 82.14 |
| 4.94                | 12.63                | 1.322                | 38.94                | 82.51 |
| 4.921               | 16                   | 1.32                 | 49.42                | 82.85 |
| 4.9                 | 19.4                 | 1.32                 | 59.91                | 83.19 |
| 4.88                | 22.81                | 1.3187               | 70.4                 | 83.40 |
| 4.865               | 25.72                | 1.318                | 79.4                 | 83.63 |
| 4.846               | 29.1                 | 1.3165               | 89.87                | 83.90 |
| 4.826               | 32.44                | 1.3146               | 100.4                | 84.31 |
| 4.64                | 64.65                | 1.3075               | 199.2                | 86.82 |
| 4.44                | 99.14                | 1.3027               | 299.59               | 88.66 |
| 4.924               | 120.48               | 1.298                | 398.5                | 87.19 |
| 4.9                 | 152                  | 1.2933               | 498.9                | 86.63 |
| 4.877               | 184.85               | 1.2886               | 599.2                | 85.65 |
| 4.852               | 218.66               | 1.284                | 698                  | 84.48 |
| 4.825               | 254.5                | 1.279                | 798.37               | 83.16 |
| 4.798               | 291.96               | 1.274                | 898.7                | 81.73 |
| 4.769               | 330.6                | 1.2696               | 1000                 | 80.53 |

18 shows the output voltage ripple of the 1.8-V rails at 4 different loads.

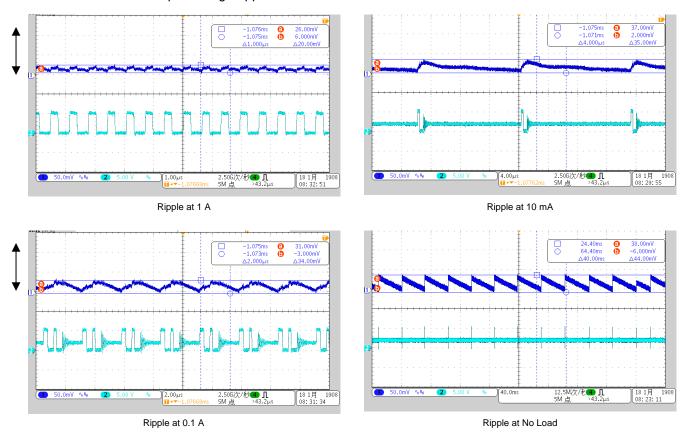


图 18. Output Voltage Ripple of 1.8 V at 4 Different Output Load



The output voltage ripple remains below 30 mVpp under a full load (1 A), light load (10 mA), 100mA and no load. This test result has a large margin, comparing the 5% requirement. The device automatically enters PSM to improve efficiency at light load when the inductor current becomes discontinuous. In PSM, the converter reduces switching frequency and minimizes current consumption.

The other power supply rails' ripple are similar to the 1.8-V rail, refer to the TLV62568/9's data sheet for more details.



Design Files www.ti.com.cn

## 4 Design Files

## 4.1 Schematics

To download the schematics, see the design files at .

#### 4.2 Bill of Materials

To download the bill of materials (BOM), see the design files at .

## 4.3 PCB Layout Recommendations

## 4.3.1 PCB Layout Guidelines

The board's PCB is set up for 6 layers; the 1, 3, 4, and 6 layers are signal layers, the 2 layer is a GND layer, and the 5 layer is a power layer. The PCB layers are shown in 图 19 through 图 24.

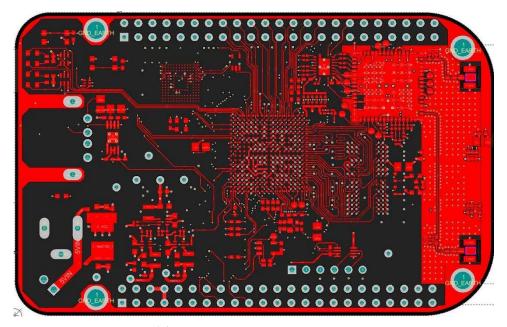


图 19. Top Layer of TIDA-01568



www.ti.com.cn Design Files

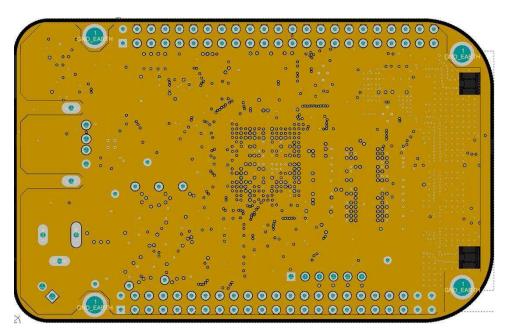


图 20. Layer 2 of TIDA-01568

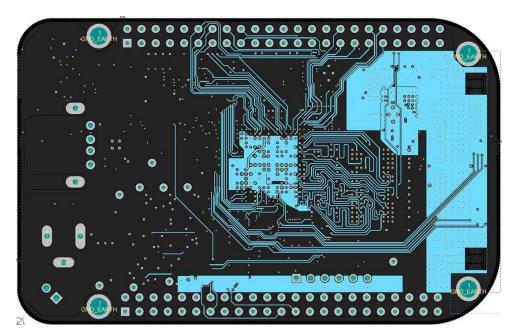


图 21. Layer 3 of TIDA-01568



Design Files www.ti.com.cn

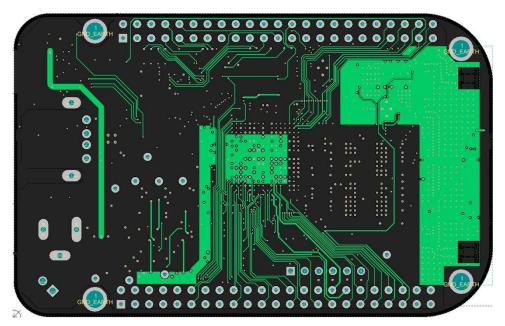


图 22. Layer 4 of TIDA-01568

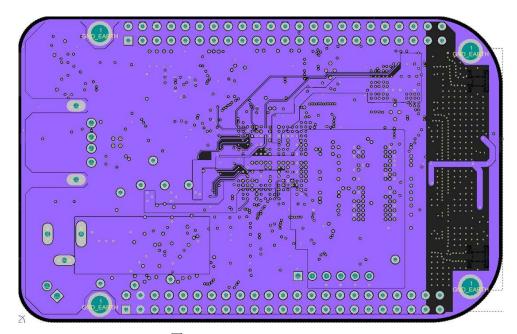


图 23. Layer 5 of TIDA-01568



www.ti.com.cn Design Files

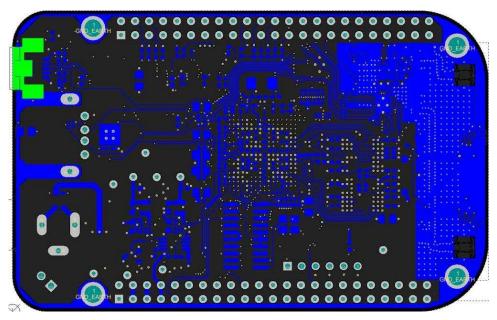


图 24. Bottom Layer of TIDA-01568

During the layout for DC-DC, coupling between different loops should be avoided. Place the input capacitor as close as possible to the device. The noise sensitive loop should be separated with high di/dt loops, so that the feedback trace should be put as far as possible from components and traces with high di/dt. Another key concern is the ground plane: it should be as large as possible to reduce noise sensitivity and improve thermal dissipation.

Another concern during layout is for the WL183xMOD: keep the proximity of ground vias close to the pad. There should be 4 vias per pad, and a complete ground pattern under the module for better thermal performance. In this design, the GND pour is added on layer 3 and layer 4 under the module.

During the layout for the antenna, use a  $50-\Omega$  impedance match on the trace to the antenna, and  $50-\Omega$  traces for the PCB layout. RF traces must have via stitching on the ground plane beside the RF trace on both sides. RF traces must have constant impedance (microstrip transmission line). RF trace bends must be gradual, with an approximate maximum bend of 45 degrees with trace mitered. RF traces must not have sharp corners. The RF trace antenna feed must be as short as possible beyond the ground reference. At this point, the trace starts to radiate.

For more details on WiLink layout, refer to the WL1837MODCOM8I WLAN MIMO and BT Module EVB for TI Sitara Platform User's Guide.

## 4.3.2 Layout Prints

To download the layer plots, see the design files at .

## 4.4 Altium Project

To download the Altium project files, see the design files at .

#### 4.5 Gerber Files

To download the Gerber files, see the design files at .



Design Files www.ti.com.cn

## 4.6 Assembly Drawings

To download the assembly drawings, see the design files at .

#### 5 Software Files

To download the software files, see the design files at .

#### 6 Related Documentation

1. Discreat Power Solution for AM437xSLVUAB1A

#### 6.1 商标

WiLink8, E2E, Sitara are trademarks of Texas Instruments. 配备基于 ARM, Cortex are registered trademarks of ARM Limited. Bluetooth is a registered trademark of Bluetooth SIG. Android is a trademark of Google, LLC. PowerVR SGX is a trademark of Imagination Technologies. Linux is a registered trademark of Linus Torvalds. microSD is a trademark of SD-3C, LLC. Wi-Fi is a registered trademark of Wi-Fi Alliance. All other trademarks are the property of their respective owners.

## 7 Terminology (Optional)

#### 8 About the Author

**ZHILONG (BRYAN) LIU** is a system engineer at Texas Instruments, responsible for developing subsystem design solutions for the Industrial appliances systems. He has system-level product experience in analog and mixed signal designs. Bryan earned his Bachelor of Technology in electrical and information engineering from Xidian University, and his Master of Technology in circuit and system from Xidian University.

#### 有关 TI 设计信息和资源的重要通知

德州仪器 (TI) 公司提供的技术、应用或其他设计建议、服务或信息,包括但不限于与评估模块有关的参考设计和材料(总称"TI 资源"),旨在帮助设计人员开发整合了 TI 产品的 应用; 如果您(个人,或如果是代表贵公司,则为贵公司)以任何方式下载、访问或使用了任何特定的 TI 资源,即表示贵方同意仅为该等目标,按照本通知的条款进行使用。

TI 所提供的 TI 资源,并未扩大或以其他方式修改 TI 对 TI 产品的公开适用的质保及质保免责声明;也未导致 TI 承担任何额外的义务或责任。 TI 有权对其 TI 资源进行纠正、增强、改进和其他修改。

您理解并同意,在设计应用时应自行实施独立的分析、评价和 判断, 且应全权负责并确保 应用的安全性, 以及您的 应用 (包括应用中使用的所有 TI 产品))应符合所有适用的法律法规及其他相关要求。你就您的 应用声明,您具备制订和实施下列保障措施所需的一切必要专业知识,能够 (1) 预见故障的危险后果,(2) 监视故障及其后果,以及 (3) 降低可能导致危险的故障几率并采取适当措施。您同意,在使用或分发包含 TI 产品的任何 应用前, 您将彻底测试该等 应用 和该等应用所用 TI 产品的 功能而设计。除特定 TI 资源的公开文档中明确列出的测试外,TI 未进行任何其他测试。

您只有在为开发包含该等 TI 资源所列 TI 产品的 应用时, 才被授权使用、复制和修改任何相关单项 TI 资源。但并未依据禁止反言原则或其他法理授予您任何TI知识产权的任何其他明示或默示的许可,也未授予您 TI 或第三方的任何技术或知识产权的许可,该等产权包括但不限于任何专利权、版权、屏蔽作品权或与使用TI产品或服务的任何整合、机器制作、流程相关的其他知识产权。涉及或参考了第三方产品或服务的信息不构成使用此类产品或服务的许可或与其相关的保证或认可。使用 TI 资源可能需要您向第三方获得对该等第三方专利或其他知识产权的许可。

TI 资源系"按原样"提供。TI 兹免除对 TI 资源及其使用作出所有其他明确或默认的保证或陈述,包括但不限于对准确性或完整性、产权保证、无屡发故障保证,以及适销性、适合特定用途和不侵犯任何第三方知识产权的任何默认保证。

TI 不负责任何申索,包括但不限于因组合产品所致或与之有关的申索,也不为您辩护或赔偿,即使该等产品组合已列于 TI 资源或其他地方。 对因 TI 资源或其使用引起或与之有关的任何实际的、直接的、特殊的、附带的、间接的、惩罚性的、偶发的、从属或惩戒性损害赔偿,不管 TI 是否获悉可能会产生上述损害赔偿,TI 概不负责。

您同意向 TI 及其代表全额赔偿因您不遵守本通知条款和条件而引起的任何损害、费用、损失和/或责任。

本通知适用于 TI 资源。另有其他条款适用于某些类型的材料、TI 产品和服务的使用和采购。这些条款包括但不限于适用于 TI 的半导体产品 (http://www.ti.com/sc/docs/stdterms.htm)、评估模块和样品 (http://www.ti.com/sc/docs/sampterms.htm) 的标准条款。

邮寄地址: 上海市浦东新区世纪大道 1568 号中建大厦 32 楼,邮政编码: 200122 Copyright © 2018 德州仪器半导体技术(上海)有限公司